

# Semiconductor phonon and charge transport Monte Carlo simulation using Geant4

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## Abstract

A phonon and charge transport simulation based on the Geant4 Monte Carlo toolkit is presented. The transport code is capable of propagating acoustic phonons, electrons and holes in cryogenic crystals. Anisotropic phonon propagation, oblique carrier propagation (with or without inter-valley scattering) and phonon emission by accelerated carriers are all taken into account. The simulation successfully reproduces theoretical predictions and experimental observations such as phonon caustics, heat pulse propagation times and mean carrier drift velocities.

Implementation of the transport code using the Geant4 toolkit ensures availability of the transport code to the wider scientific community.

*Keywords:*

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## 1. Introduction

We present a Monte Carlo simulation of phonon and charge transport in semiconductor crystals using Geant4. Geant4 is a sophisticated C++ based Monte Carlo simulation toolkit maintained by an international collaboration and freely available under an open source license [1] [2]. The toolkit was originally developed in support of High Energy Physics (HEP) experiments and

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provides functionality for the simulation of the passage of particles through complex geometries and materials. It aims to accurately simulate all matter-particle interactions and has become an important tool both for HEP particle accelerator based experiments building Detector Monte Carlo(DMC) simulations and experiments wishing to estimate backgrounds from environmental or cosmic ray radiation sources [3][4].

In it's current incarnation, the Geant4 toolkit is entirely focused on free particles and does not take into account crystal physics and conduction/valence band interactions of the low energy charge carriers and phonons relevant to condensed matter physics. This paper documents our effort to build a cohesive Geant4 Condensed Matter Physics Monte Carlo simulation toolkit, G4CMP. The original purpose of this project was to accurately reproduce data from the dark-matter direct detection experiment, Cryogenic Dark Matter Search (CDMS) [6][7][8]. The CDMS detectors are cylindrical Ge crystals of approximately size 75 mm in diameter with a height of 25 mm [9], cooled to  $\sim 60$  mK. Dark matter particles may recoil from Ge nuclei via the weak force and thus create phonons and free electron-hole pairs within the crystal [5]. Electron-hole pairs are drifted to the crystal faces using a small drift field ( $\sim$  V/m) where they are collected. Phonons are detected by Transition Edge Sensor (TES) bolometers. We aim to reproduce all of these processes in our Monte-Carlo.

The phonon and charge transport code described models all physics processes believed to be relevant to phonon and charge collection at cryogenic temperatures. This includes anisotropic phonon transport/phonon focusing, phonon isotope scattering, anharmonic downconversion, oblique carrier propagation (with and without inter-valley scattering) and emission of Luke-Neganov phonons by accelerated carriers. We believe that the resulting G4CMP framework is sufficiently general that it is useful to other experiments employing cryogenic charge or phonon detectors.

## 2. Phonon Transport

Phonon transport was the first component of the G4CMP framework to be developed and early results were presented at LTD-14 [4]. Since the phonon transport code described here is intended for temperatures  $T < 1$ K, scattering off thermally excited background phonons is ignored. Currently, only acoustic phonons are simulated.

## 2.1. Anisotropic transport and phonon focusing

Phonons are quantized vibrations of the crystal lattice. The propagation of phonons is governed by the three-dimensional wave equation [15]:

$$\rho\omega^2 e_i = C_{ijkl} k_j k_l e_i \quad (1)$$

where  $\rho$  is the crystal mass density,  $\omega$  is the phonon frequency,  $\vec{e}$  is the polarization vector,  $\vec{k}$  is the wave vector and  $\vec{C}_{ijkl}$  is the elasticity tensor.

For any given wave vector,  $\vec{k}$ , Eq. 1 has three eigenvalues,  $\omega$ , and three eigenvectors,  $\vec{e}$ . These correspond to the three different polarization states *Fast Transverse (FT)*, *Slow Transverse (ST)* and *Longitudinal (L)*. The actual direction and velocity of propagation of phonons is given by the group velocity vector  $\vec{v}_g = d\omega/dk$ . The group velocity can be calculated by interpreting  $\omega$  in Eq. 1 as a function of  $\vec{k}$ :

$$\vec{v}_g = \frac{d\omega(\vec{k})}{d\vec{k}} = \nabla_{\vec{k}}\omega(\vec{k}) \quad (2)$$

Due to the anisotropy in  $C_{ijkl}$ , Eq. 2 yields a group velocity  $\vec{v}_g$  which is not parallel to the phonon momentum  $\hbar\vec{k}$ . Instead, phonons are focused onto propagation directions which correspond to the highest density of eigenvectors  $\vec{k}$ . This focusing gives rise to caustics when observing the energy distribution resulting from a point-like phonon source isotropic in  $\vec{k}$ -space. The resulting caustics can be observed using micro-calorimeters [11]. Figure 1 shows that the caustics simulated by the Geant4 phonon transport code are in good agreement with experimental observations.

For the purposes of the G4CMP phonon transport code, the wave equation is not solved in real time but rather a look-up table is generated which maps  $\vec{k}$  onto  $\vec{v}_g$ . Bilinear interpolation is used to generate a continuous mapping function. Phonon focusing and methods for solving the three-dimensional wave equations are treated Wolfe's book [15].

## 2.2. Phonon processes

In addition to the phonon equation of motion, which is given by the three dimensional wave equation Eq. 1, two processes are relevant to acoustic phonon transport in cryogenic crystals: Isotope scattering and anharmonic down conversion[12][13][16]. The scattering and downconversion rates for phonons in the cryogenic crystal are given by [13]:

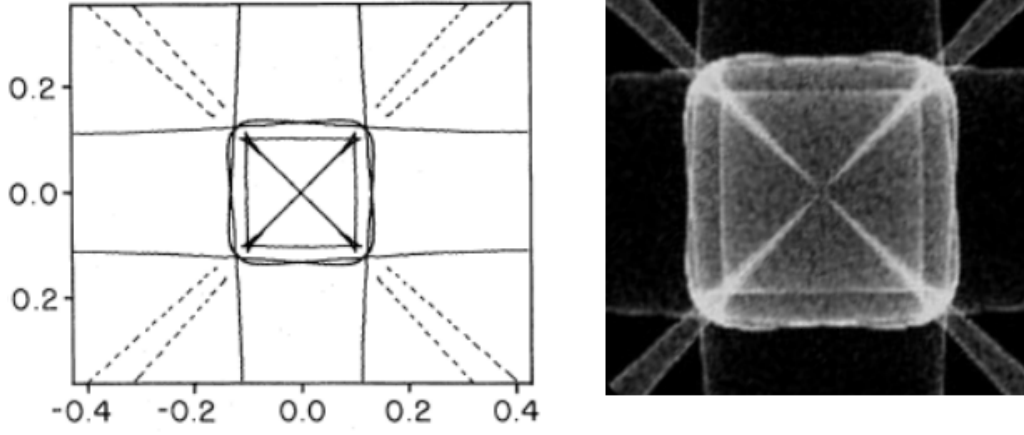


Figure 1: **Left:** outline of phonon caustics in Ge as predicted by Nothrop and Wolfe [11]. **Right:** Phonon caustics as simulated using the Geant4 phonon transport code. This results is in good agreement with both the theoretical prediction and experimental observations reported by Nothrop and Wolfe [11]

$$\Gamma_{scatter} = B\nu^4 \quad (3)$$

$$\Gamma_{anh} = A\nu^5 \quad (4)$$

where  $\Gamma_{scatter}$  is the number of scattering events per unit time,  $\Gamma_{anh}$  is the number of anharmonic downconversion events per unit time,  $\nu$  is the phonon frequency and  $A, B$  are constants of proportionality derived from the elasticity tensor. Their value for Ge was discussed in [4] and methods for their derivation can be found in [12] and [13].

The isotope scattering process occurs when a phonon interacts with an isotopic substitution site in the lattice. It is effectively an elastic scattering process during which we assume the phonon momentum vector to be randomized. During this scattering process the phonon polarization state can change freely between the three states  $L, ST, FT$ . The branching ratio between the three polarizations is determined by the relative density of allowed states for each polarization. This change between polarization states is often referred to as mode mixing.

The anharmonic down conversion process causes a single energetic phonon to decay into two phonons of reduced energy. This process conserves energy but not momentum, since momentum is exchanged with the crystal lattice.

In theory all three polarization states can decay, however, the downconversion rate of  $L$ -phonons completely dominates the energy evolution of the phonon system, with downconversion events from other polarization states being negligible [13].

Eqs. 3 and 4 show that both process rates strongly depend on phonon energy  $\hbar\nu$ . High energy phonons ( $\nu$  of order THz) start out in a diffusive regime with high isotope scattering and downconversion rates and mean free paths of order microns. Once a few downconversion events have occurred, phonon mean free paths increase to be of order the size of a typical CDMS detector ( $\sim 0.1$  m). This transition from a diffuse to a ballistic transport mode is commonly referred to as “quasi-diffuse” and controls the time evolution of phonon heat pulses. Simulation of heat pulses using our Geant4 transport code was described in [4] and shows good agreement with experiment. Anharmonic downconversion and isotope scattering are well understood and are discussed in great detail in the literature [12][13][15][16].

### 3. Charge Transport

At present, the charge transport component of the G4CMP framework only includes transport in germanium. For charge carrier transport in germanium, there are two processes to consider: acceleration by an applied electromagnetic field, and emission of Neganov-Luke phonons.

When an incoming particle scatters in the germanium crystal, electron-hole pairs are produced. In the example of the CDMS dark matter detectors, the charge carriers are drifted by an external electric field to the surfaces of the detector.

#### 3.1. Neganov-Luke Phonons

As the charge carriers are accelerated through the crystal, they emit phonons in a process that is analogous to Cerenkov radiation.

##### 3.1.1. Holes

Charge carrier-hole scattering is an elastic process, conserving energy and momentum.

Figure 2: A charge carrier has initial wavevector  $\vec{k}$  and emits a Neganov-Luke phonon with wavevector  $\vec{q}$  [17]

From conservation of energy and momentum,  $k'^2 = k^2 + q^2 - 2kq \cos \theta$  and  $q = 2(k \cos \theta - k_L)$ , with  $k_L$  defined as  $k_L = mv_L/\hbar$ , where  $v_L$  is the longitudinal phonon phase speed. Solving for  $\phi$ ,

$$\cos \phi = \frac{k^2 - 2k_s(k \cos \theta - k_s) - 2(k \cos \theta - k_s)^2}{k \sqrt{k^2 - 4k_s(k \cos \theta - k_s)}} \quad (5)$$

Where  $k_L = mv_L/\hbar$ . Using Fermi's Golden Rule, we can determine a scattering rate [17],

$$1/\tau = \frac{v_L k}{3l_0 k_L} \left(1 - \frac{k_L}{k}\right)^3 \quad (6)$$

With an angular distribution of,

$$P(k, \theta) d\theta = \frac{v_L}{l_0} \left(\frac{k}{k_L}\right)^2 \left(\cos \theta - \frac{k_L}{k}\right)^2 \sin \theta d\theta \quad (7)$$

Where  $0 \leq \theta \leq \arccos k_L/k < \pi/2$  and  $l_0$  is a characteristic scattering length defined as  $l_0 = \frac{\pi \hbar^4 \rho}{2m^3 C^2}$  with  $C$  being the deformation potential constant for Ge [17].

### 3.1.2. Electrons

The effective mass of the hole in germanium is a scalar, so its propagation is simple. The electron, however, has a tensor effective mass.

Figure 3: Conduction and valence bands in Ge. At present, the G4CMP framework only simulates electrons propagating through the L conduction band. At sufficiently low temperature and applied field, this should match reality well [17].

For a coordinate system with one axis aligned with the principle axis of the conduction valley, the electron's equation of motion is,

$$\frac{eE_i}{m_i} = \frac{dv_i}{dt} \quad (8)$$

However, to simplify the electron propagation, we transform to a coordinate system in which the constant energy surfaces are spherical. In that space,  $v_i^* = v_i/\sqrt{m_c/m_i}$ , where  $m_c$  is given by  $3/m_c = 1/m_{\parallel} + 2/m_{\perp}$ . And so,

$$\frac{eE_i^*}{m_c} = \frac{dv_i^*}{dt} \quad (9)$$

Once the coordinate system is rotated into the conduction valley frame, a Herring-Vogt transformation is then applied,

$$T_{HV} = \begin{pmatrix} \sqrt{\frac{m_c}{m_{\parallel}}} & 0 & 0 \\ 0 & \sqrt{\frac{m_c}{m_{\perp}}} & 0 \\ 0 & 0 & \sqrt{\frac{m_c}{m_{\perp}}} \end{pmatrix} \quad (10)$$

From this space, the same recipe that applied to holes for propagation and Neganov-Luke phonon emission can be followed for electrons. One potential issue is the back-transform into real space. Because the HV matrix is not unitary, it won't conserve energy. To mitigate the issue, the phonon's momentum magnitude is kept from the HV space and the back-transform is only used to determine the angular distribution [17].

### 3.2. Inter Valley Scattering

Electron propagation as discussed in the previous section, has one particularly interesting feature that electrons propagate through the crystal in one of four distinct valleys [18, 17]. Electrons are not bound to those valleys permanently, however, and can scatter between valleys. This process is known as inter-valley scattering and occurs in one of two ways: 1. an electron scatters off the lattice or 2. off an impurity in the crystal structure [19]. The rate for both processes is dependent on the electric field strength with lattice scattering being the dominant factor in larger fields ( $\gtrsim 5$  V/m), while impurity scattering dominates in lower fields ( $\sim 1$  V/m). The EDELWEISS [20] collaboration determined the scattering rates as a function of the electric field for typical Ge crystals [19]. We use the results obtained in these studies to set the inter-valley scattering amplitude in the Geant4 framework and compare it to previous implementations of the charge transport code [18, 17]. The result of electrons and holes propagating through 2.54 cm of Ge in an 0.5 V/m electric field is shown in Figure 4. The top two panels show the result with inter-valley scattering turned on while the bottom two panels show the result for inter-valley scattering turned off. The panels on the right show the results for the legacy simulation [18, 17] with somewhat less statistics than the Geant4 simulations. The bottom two panels also show

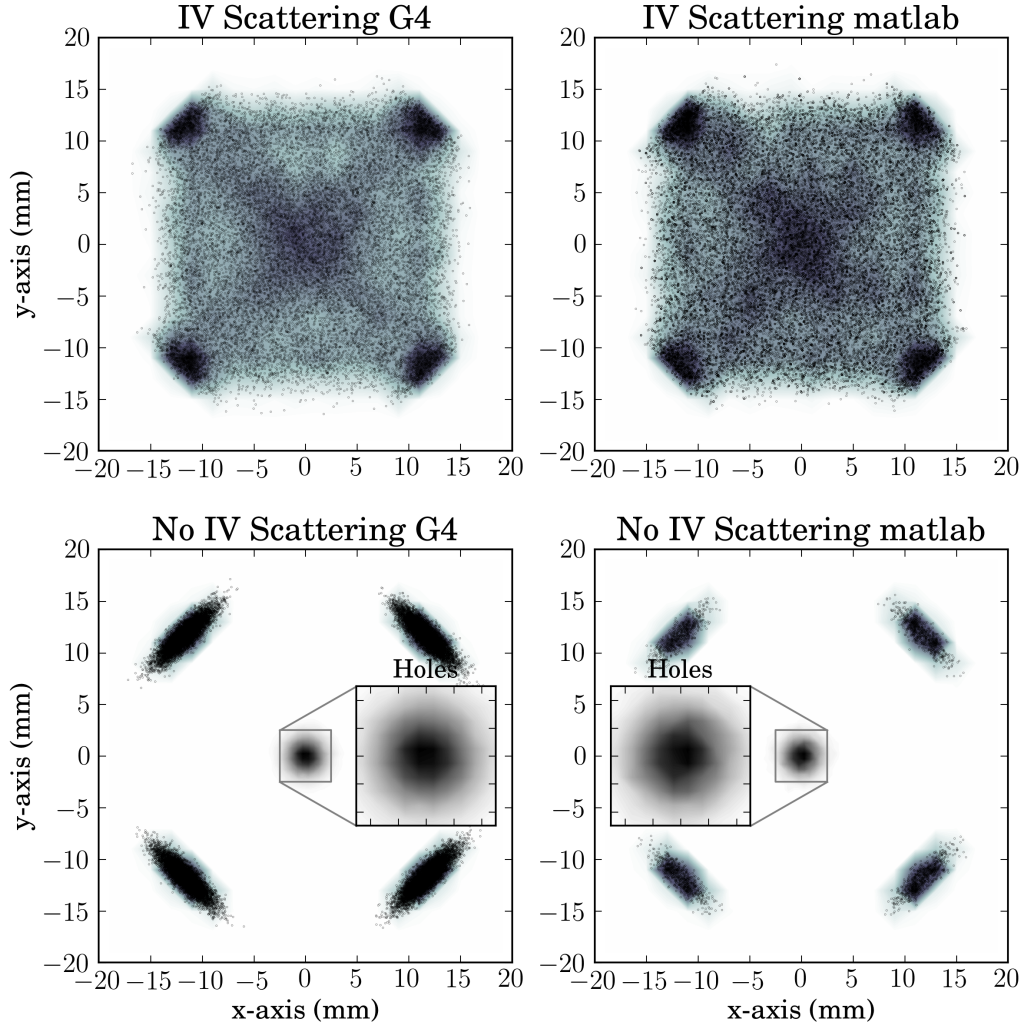


Figure 4: **Left:** Geant4 simulations **Right:** legacy MATLAB simulations. **Top Row:** Simulations with inter-valley scattering turned on, **Bottom Row:** Simulations with inter-valley scattering turned off, including hole transport through the crystal.



the hole transport through the crystal with the result being the gray contour in the center.

#### 4. Conclusion

We presented Monte Carlo transport code capable of propagating phonons on a cryogenic crystal lattice (Section 2) as well as drifting electron/hole pairs, taking into account conduction band anisotropy (Section 3). The results produced by the transport code are in good agreement with experiment, reproducing phonon caustics and carrier drift velocity with acceptable accuracy. It was shown that this code reproduces heat pulse propagation and dispersion in cryogenic Ge crystals with acceptable accuracy in [4]. The entire transport code is written in Geant4 and is easily adaptable for crystals other than Ge provided that the Voigt-contracted elasticity tensor and effective carrier masses are known. The Geant4 framework makes it possible to enhance and extend the code presented here. The phonon transport code is already freely available as part of the examples provided with Geant4 v9.6p02, and newer. We hope that the work presented here will establish Geant4 as a tool in condensed matter physics and cryogenic calorimeter design as well as motivating others to add to the G4CMP framework.

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